### Switching Diodes

## Panasonic

# MA3X152D (MA152WA), MA3X152E (MA152WK)

## Silicon epitaxial planar type

For high-speed switching circuits

#### Features

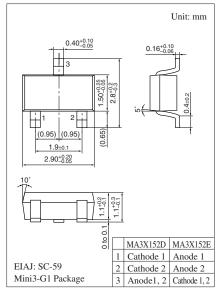
- Short reverse recovery time t<sub>rr</sub>
- Small terminal capacitance, C<sub>t</sub>

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter		Symbol	Rating	Unit
Reverse voltage		V <sub>R</sub>	80	V
Maximum peak reverse voltage		V <sub>RM</sub>	80	V
Forward current	Single	$I_{\rm F}$	100	mA
	Double		150	
Peak forward	Single	$I_{FM}$	225	mA
current	Double		340	
Non-repetitive peak	Single	I <sub>FSM</sub>	500	mA
forward surge current $^{*}$	Double		750	
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to +150	°C

Note) \*: t = 1 s

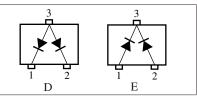
#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$



#### Marking Symbol

• MA3X152D: MO • MA3X152E: MU

#### Internal Connection

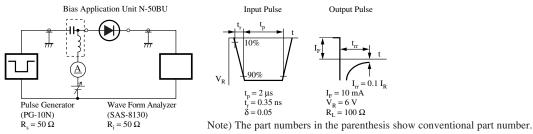


Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage		$V_{\rm F}$	$I_F = 100 \text{ mA}$			1.2	V
Reverse voltage		V <sub>R</sub>	$I_R = 100 \ \mu A$	80			V
Reverse current		I <sub>R</sub>	V <sub>R</sub> = 75 V			100	nA
Terminal capacitance	MA3X152D	Ct	$V_{R} = 0 V, f = 1 MHz$			15	pF
	MA3X152E					2	
Reverse recovery time *	MA3X152D	t <sub>rr</sub>	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}$			10	ns
	MA3X152E		$I_{\rm rr}$ = 0.1 $I_{\rm R}$ , $R_{\rm L}$ = 100 $\Omega$			3	

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring method for diodes.

2. Absolute frequency of input and output is 100 MHz.

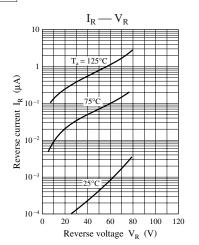
3. \*: t<sub>rr</sub> measurement circuit

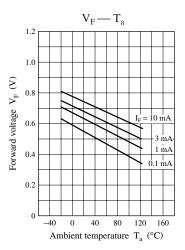


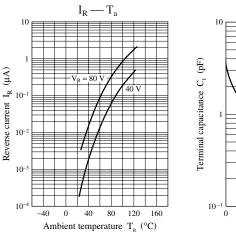
Publication date: November 2003

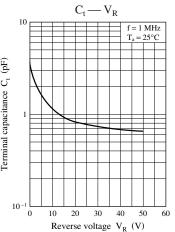
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#### Characteristics chart of MA3X152D $I_F - V_F$ 10<sup>3</sup> 10<sup>2</sup> Forward current I<sub>F</sub> (mA) 10 = 125°C 1 75°C 25°C 20°C 10- $10^{-2}$ 0.2 0.4 0.6 0.8 1.0 Forward voltage $V_{\rm F}$ (V) 0 0.2 1.0 1.2



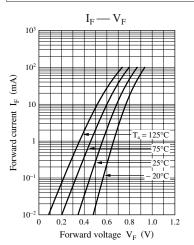


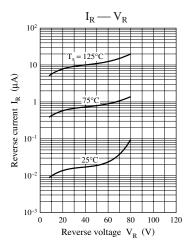




#### Characteristics chart of MA3X152E

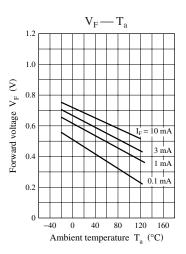
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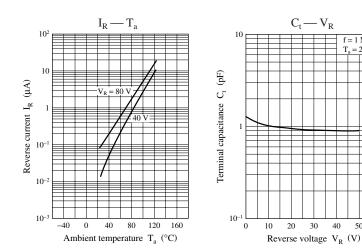




f = 1 MHz $T_a = 25^{\circ}C$ 

40 50 60





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